

High PSRR Low Noise 300mA LDO

General Description

The ET523XX family are the 300mA LDO with auto discharge function, it uses an advanced CMOS process and a PMOSFET pass device to achieve high power supply rejection ratio (PSRR), low noise, low dropout, low ground current, fast start-up and excellent output accuracy.

The ET523XX family are stable with a 1.0 μ F ceramic output capacitor, uses a precision voltage reference and feedback loop to achieve excellent Regulation and transient response.

The ET523XX family offered in small DFN4 and SOT23-5 package, which are ideal for small form factor portable equipment.

Features

- Wide Input Voltage Range from 1.7V to 5.5V
- Up to 300mA Load Current
- Standard Fixed Output Voltage Options: 1.2V to 3.3V
- Very Low IQ is 50 μ A typical
- Low Dropout is typical 240mV@2.8V at 300mA Load
- Very High PSRR: 75dB at 1KHz
- Very Low Noise is 40 μ Vrms at 1.8V output
- Excellent Load/Line Transient Response
- Part No. and Package

Part No.	Package	Packing Option	MSL
ET523XXYB	DFN4(1mm $\times$ 1mm)	Tape and Reel, 10K	Level 1
ET523XXB	SOT23-5	Tape and Reel, 3K	Level 3

Applications

- Smart Phones and Cellular Phones
- Digital Still Cameras
- Portable instruments

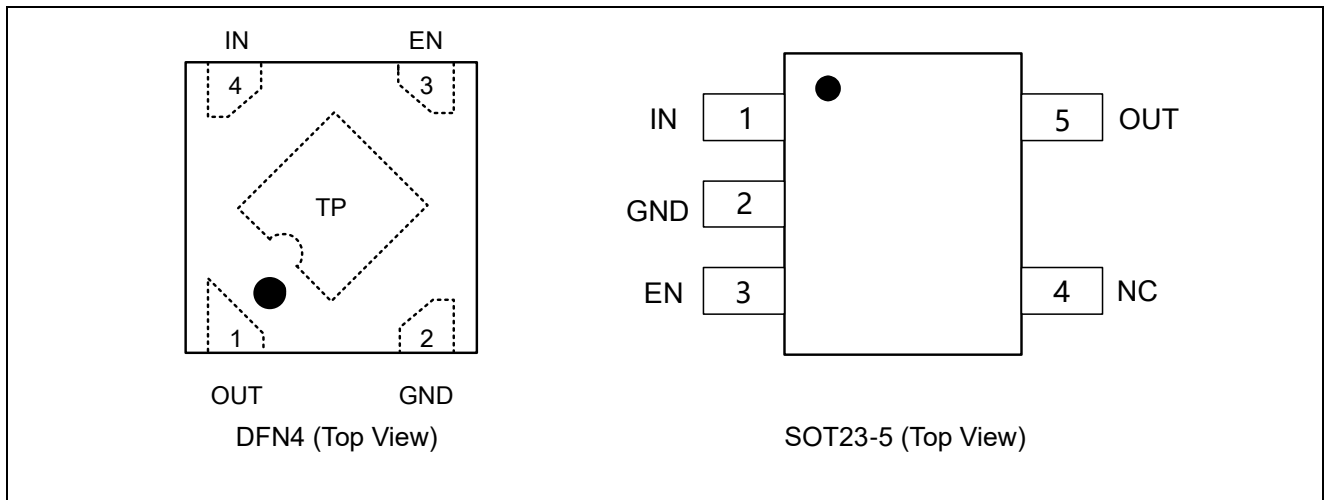
ET523XX

Device information

ET 523 XX X B

<u>XX</u> Output Voltage		<u>X</u> Package		<u>B</u> Auto-discharge Function	
XX	1.8~3.3V	/	SOT23-5	B	With Auto-discharge
		Y	DFN4-1.0×1.0		

Pin Configuration

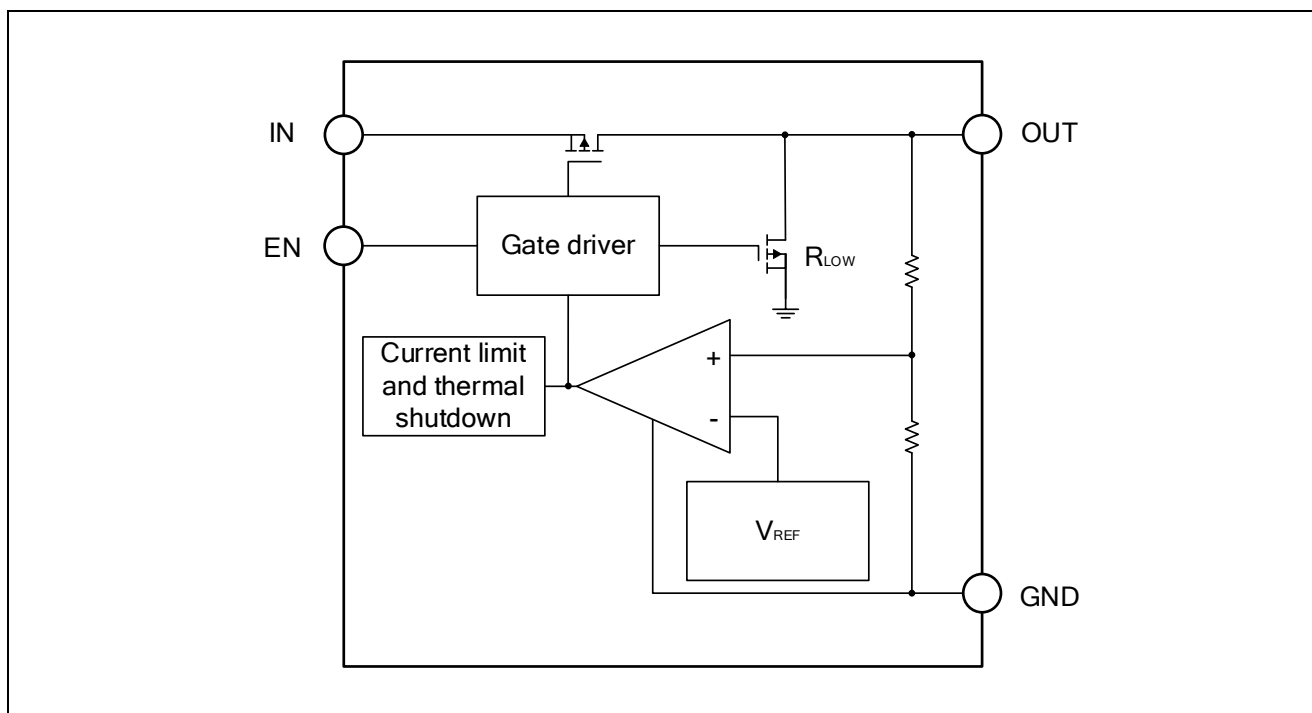


Pin Function

Pin NO.		Symbol	Pin Description
DFN4	SOT23-5		
1	5	OUT	Output Pin
2	2	GND	Power Supply Ground
3	3	EN	Chip Enable Pin (Active "H")
4	1	IN	Power Supply Input Voltage
TP	4	Thermal Pad / NC	Thermal pad for DFN4(1×1) package, connect to GND or leave floating. Do not connect to any potential other than GND. NC for SOT23-5 no connection.

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Block Diagram



Functional Description

Input Capacitor

A 1 μ F ceramic capacitor is recommended to connect between V_{IN} and GND pins to decouple input power supply glitch and noise. The amount of the capacitance may be increased without limit. This input capacitor must be located as close as possible to the device to assure input stability and less noise. For PCB layout, a wide copper trace is required for both V_{IN} and GND.

Output Capacitor

An output capacitor is required for the stability of the LDO. The recommended output capacitance is 0.47 μ F or larger, the effective capacitance needs to take the DC-Bias characteristic, tolerance and temperature into consideration, and temperature characteristics is X7R or X5R. Higher capacitance values help to improve load/line transient response. The output capacitance may be increased to keep low undershoot/overshoot. Place output capacitor as close as possible to OUT and GND pins.

ON/OFF Input Operation

The ET523XX is turned on by setting the EN pin high, and is turned off by pulling it low. If this feature is not used, the EN pin should be tied to IN pin to keep the regulator output on at all time.

Ultra-Fast Start-up

After enabled, the ET523XX is able to provide full power in as little as tens of microseconds, typically 60 μ s. This feature will help load circuitry move in and out of standby mode in real time, eventually extend battery life for mobile phones and other portable devices.

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Current Limit Protection

When output current at the OUT pin is higher than current limit threshold or the OUT pin, the current limit protection will be triggered and clamp the output current to approximately 500mA to prevent over-current and to protect the regulator from damage due to overheating.

Thermal Shutdown Protection

Thermal protection disables the output when the junction temperature rises to approximately +155°C, allowing the device to cool down. When the junction temperature reduces to approximately +130°C the output circuitry is enabled again. Depending on power dissipation, thermal resistance, and ambient temperature, the thermal protection circuit may cycle on and off. This cycling limits the heat dissipation of the regulator, protecting it from damage due to overheating.

Absolute Maximum Ratings

Symbol	Parameters (Items)		Value	Unit
V _{IN}	IN Voltage		-0.3 to 6.5	V
V _{EN}	Input Voltage (EN Pin)		-0.3 to V _{IN} +0.3	V
V _{OUT}	Output Voltage		-0.3 to V _{IN} +0.3	V
I _{MAX}	Maximum Load Current		500	mA
V _{ESD}	Human Body Model (JEDEC JS-001)		±4000	V
	Charged Device Model (JESD22-C101)		±1500	
R _{θJA}	Junction-to-ambient thermal resistance	DFN4	250	°C/W
		SOT23-5	TBD	
T _J	Operating Junction Temperature		-40 to 150	°C
T _{STG}	Storage Temperature		-65 to 150	°C
T _{SLD}	Lead Temperature (Soldering, 10 sec)		300	°C

Recommended Operating Conditions

Symbol	Item	Rating	Unit
V _{IN}	Input Voltage	1.7 to 5.5	V
I _{OUT}	Output Current	0 to 300	mA
T _A	Operating Ambient Temperature	-40 to 85	°C
C _{IN}	Effective Input Ceramic Capacitor Value	0.47 to 4.7	μF
C _{OUT}	Effective Output Ceramic Capacitor Value	0.47 to 4.7	μF

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Electrical Characteristics⁽¹⁾

($V_{IN}=V_{EN}=V_{OUT}+1.0V$, $I_{OUT}=1mA$, $C_{IN}=1\mu F$, $C_{OUT}=1\mu F$, Typical values are at $T_A=25^\circ C$ unless otherwise noted)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
V_{IN}	Input Voltage Operation Range		1.7		5.5	V
V_{DROP}	Dropout Voltage ⁽²⁾	$V_{OUT} = 1.2V$, $I_{OUT} = 300mA$			500	mV
		$V_{OUT} = 1.8V$, $I_{OUT} = 300mA$		275	430	mV
		$V_{OUT} = 2.8V$, $I_{OUT} = 300mA$		265	400	mV
		$V_{OUT} = 3.0V$, $I_{OUT} = 300mA$		250	380	mV
		$V_{OUT} = 3.3V$, $I_{OUT} = 300mA$		250	380	mV
I_{Q_ON}	DC Supply Quiescent Current	Active mode: $V_{EN} = V_{IN}$		50	90	μA
I_{Q_OFF}	DC Supply Shutdown Current	$V_{EN}=0V$		0.01	1	μA
V_{OUT}	Regulated Output Voltage	$I_{OUT} = 1mA$, $-40^\circ C \leq T_A \leq 85^\circ C$	-2		2	%
Reg_{LINE}	Output Voltage Line Regulation	$V_{IN} = V_{OUT} + 1V$ to $5.5V$, $I_{OUT} = 10mA$		0.03	0.2	%/V
Reg_{LOAD}	Output Voltage Load Regulation	I_{OUT} from $0mA$ to $300mA$		15	40	mV
t_{ON}	Soft-start Time	From enable to power on		60		μs
I_{LIMIT}	Current Limit	$R_{LOAD} = 1\Omega$	330			mA
I_{SHORT}	Short Current Limit	$V_{OUT} = 0V$		60		mA
$PSRR^{(3)}$	Power Supply Rejection Ratio	$F = 1kHz$, $C_{OUT} = 1\mu F$, $I_{OUT} = 20mA$		75		dB
		$F = 10kHz$, $C_{OUT}=1\mu F$, $I_{OUT} = 30mA$		65		dB
$e_N^{(3)}$	Output Noise	10Hz to 100kHz, $I_{OUT} = 200mA$, $V_{OUT} = 2.8V$, $C_{OUT} = 1\mu F$		70		μV_{RMS}
		10Hz to 100kHz, $I_{OUT} = 200mA$, $V_{OUT} = 1.8V$, $C_{OUT} = 1\mu F$		42		
V_{ENL}	EN Low Threshold				0.4	V
V_{ENH}	EN High Threshold		1.2			V
I_{EN}	EN Pin Input Current	$V_{EN} = 0V$		0	0.1	μA
R_{PD}	EN pull-down resistance		0.7	1	1.3	M Ω
R_{DIS}	Output resistance of auto discharge at off state	$EN = 0V$, $V_{IN} = 5V$		70		Ω

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Electrical Characteristics(Continued)⁽¹⁾

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
T _{SD} ⁽³⁾	Over-temperature Shutdown Threshold	T _J rising		155		°C
T _{HYS} ⁽³⁾	Over-temperature Shutdown Hysteresis	T _J falling from shutdown		20		°C

Notes:

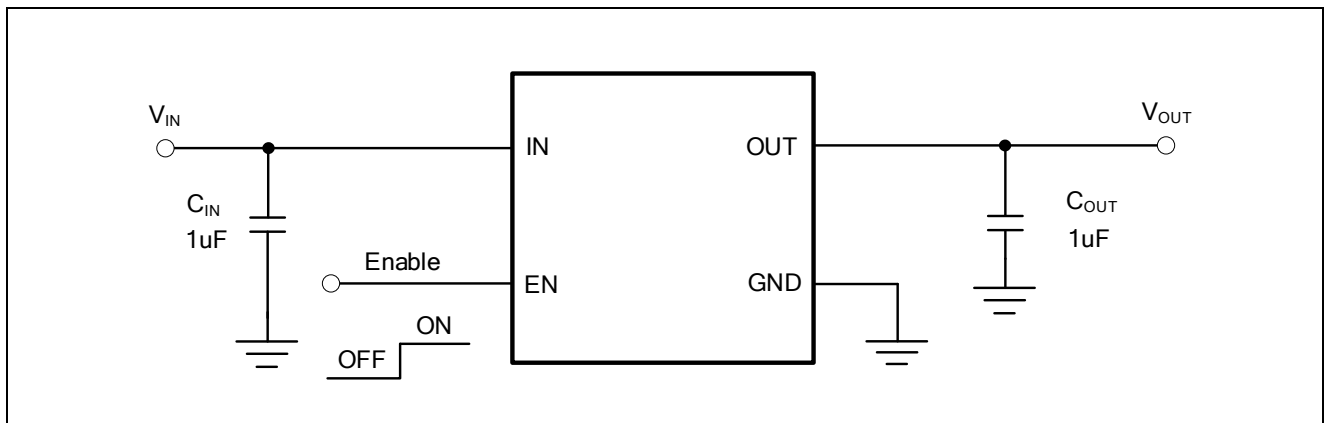
1: Production test at +25°C. Specifications over the temperature range are guaranteed by design and characterization.

2: The minimum operating voltage is 1.7V. The calculation formula is as follows:

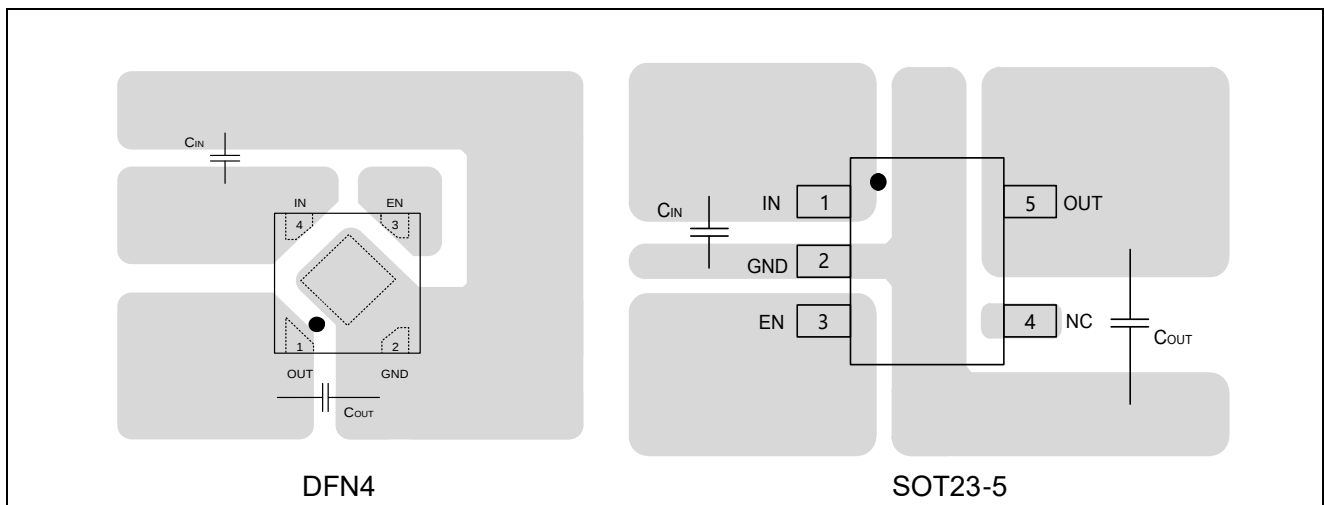
$$V_{\text{DROP}} = V_{\text{IN(min)}} - V_{\text{OUT}}$$

3: Guaranteed by design and characterization. Not a FT item.

Application Circuits



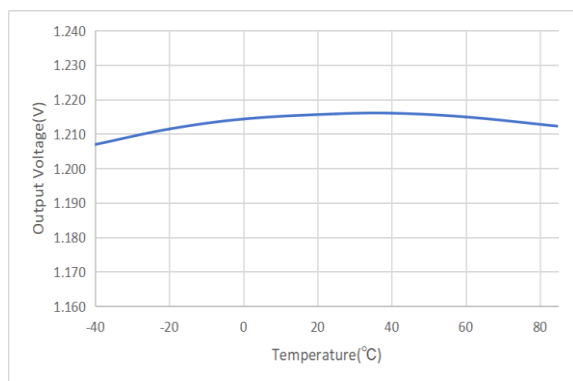
PCB Layout Guide



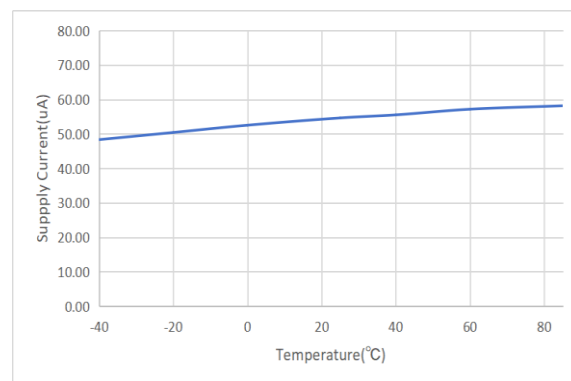
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Typical Characteristics

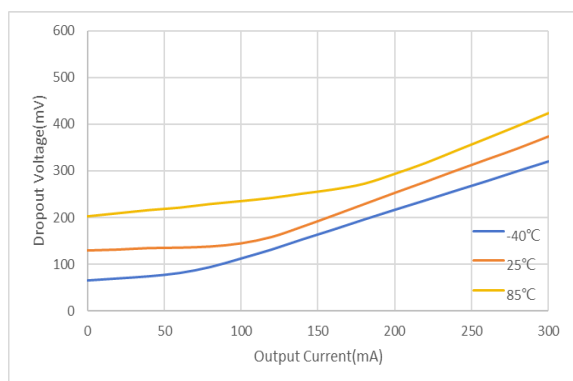
(ET52312YB, $V_{IN}=2.2V$, $I_{OUT}=1mA$, C_{IN} = Ceramic $1.0\mu F$, C_{OUT} = Ceramic $1.0\mu F$, $T_A=-40^{\circ}C\sim 85^{\circ}C$)



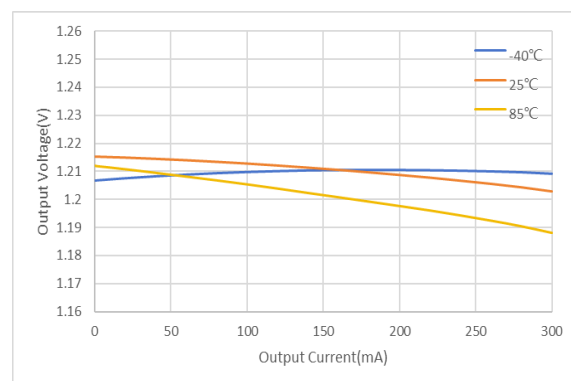
Output Voltage VS Temperature



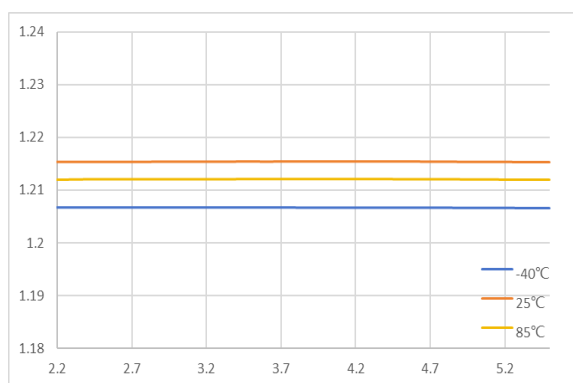
Supply Current VS Temperature



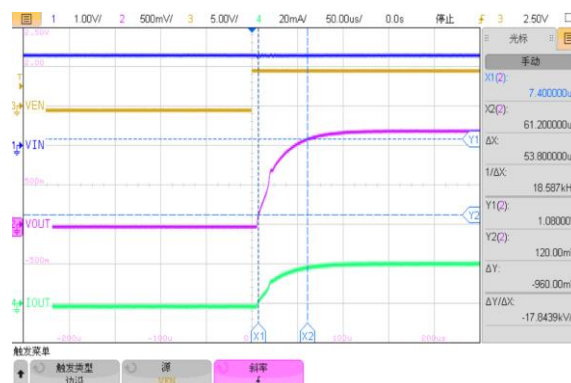
Dropout Voltage VS Output Current



Output Voltage VS Output Current



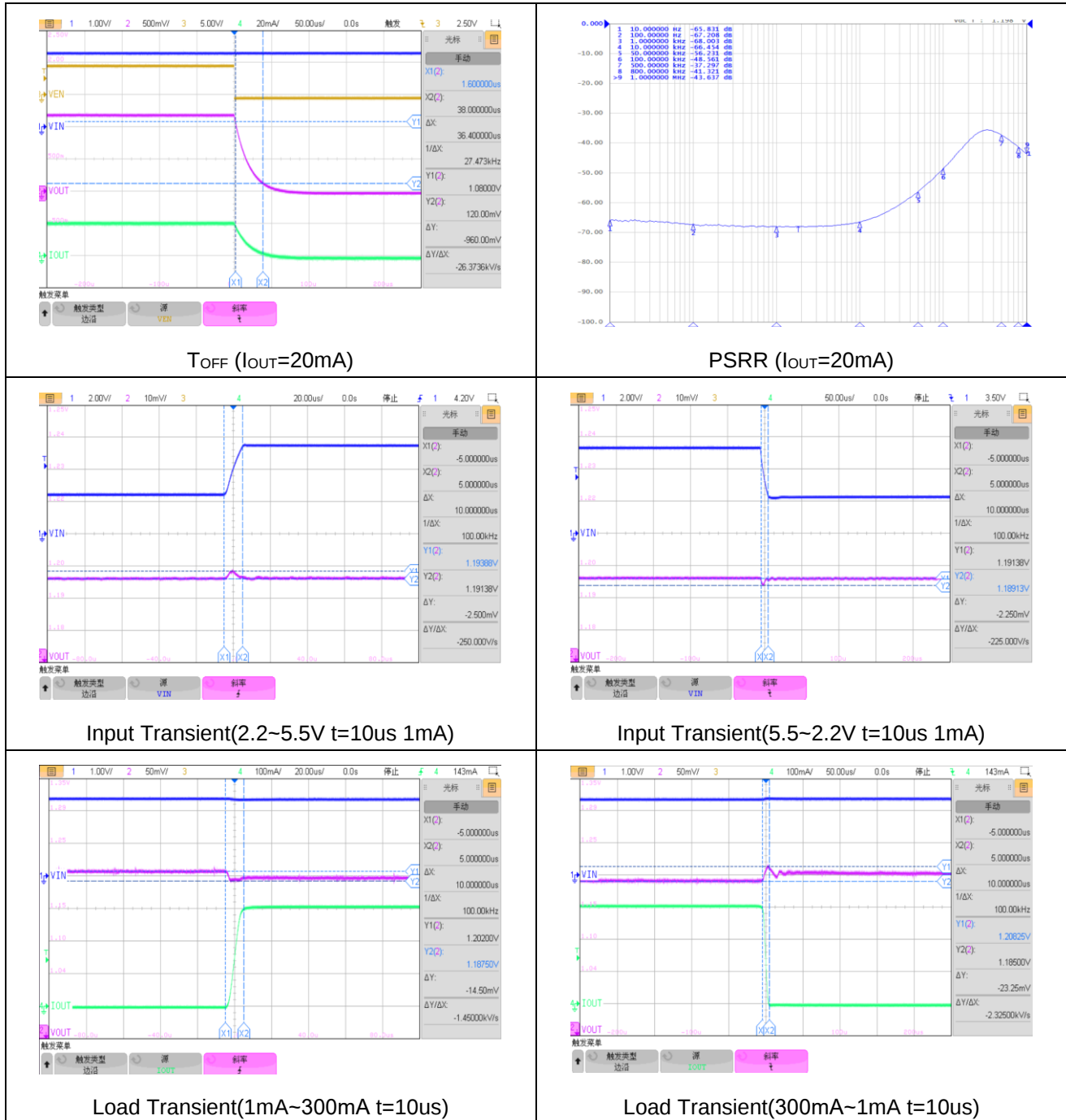
Output Voltage VS Input Voltage



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Typical Characteristics(Continued)

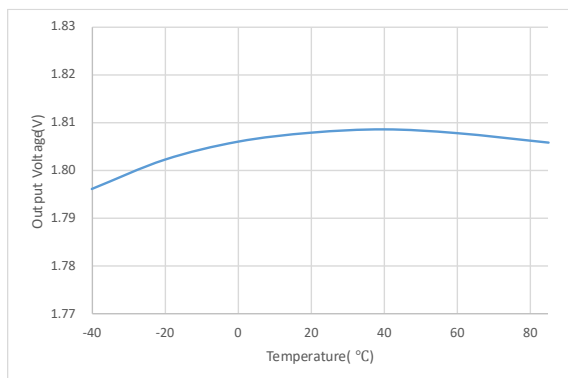
(ET52312YB, $V_{IN}=2.2V$, $I_{OUT}=1mA$, C_{IN} = Ceramic $1.0\mu F$, C_{OUT} = Ceramic $1.0\mu F$, $T_A=-40^{\circ}C\sim 85^{\circ}C$)



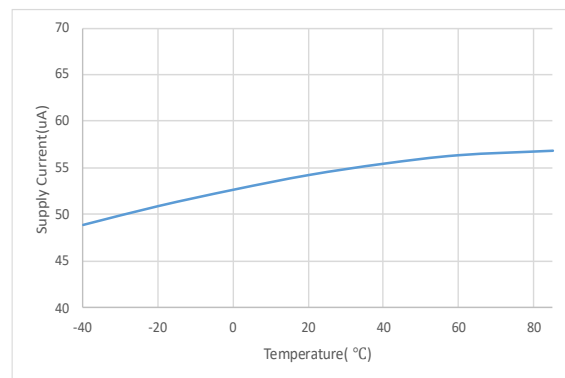
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Typical Characteristics(Continued)

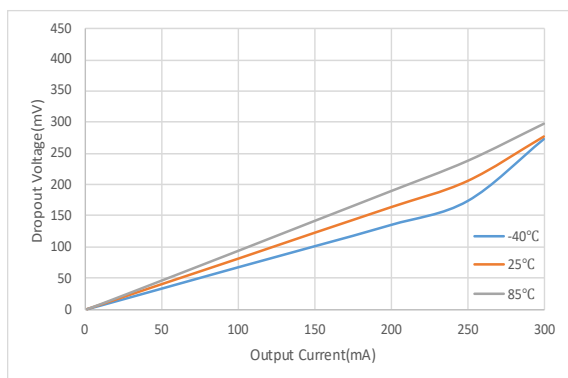
(ET52318YB, $V_{IN}=2.8V$, $I_{OUT}=1mA$, C_{IN} = Ceramic $1.0\mu F$, C_{OUT} = Ceramic $1.0\mu F$, $T_A=-40^{\circ}C\sim 85^{\circ}C$)



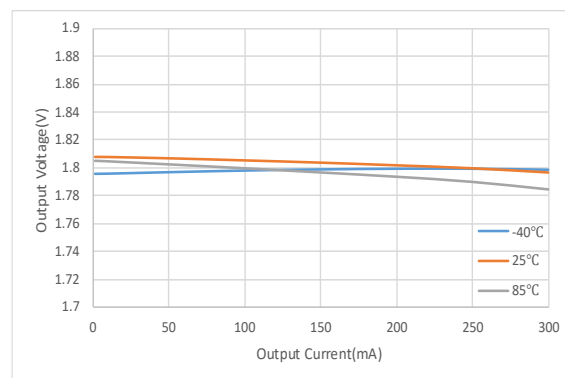
Output Voltage VS Temperature



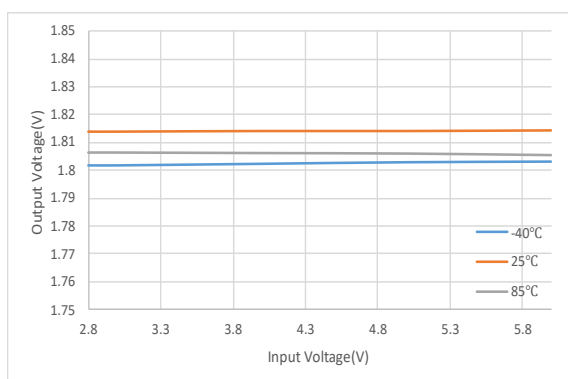
Supply Current VS Temperature



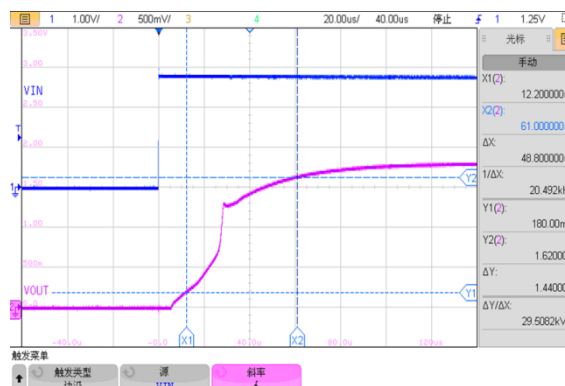
Dropout Voltage VS Output Current



Output Voltage VS Output Current



Output Voltage VS Input Voltage

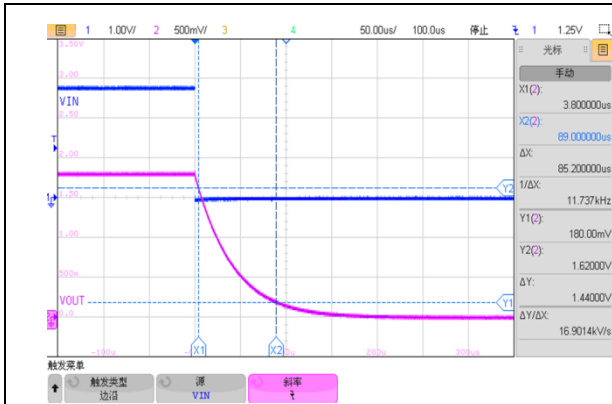


TON (I_{OUT}=30mA)

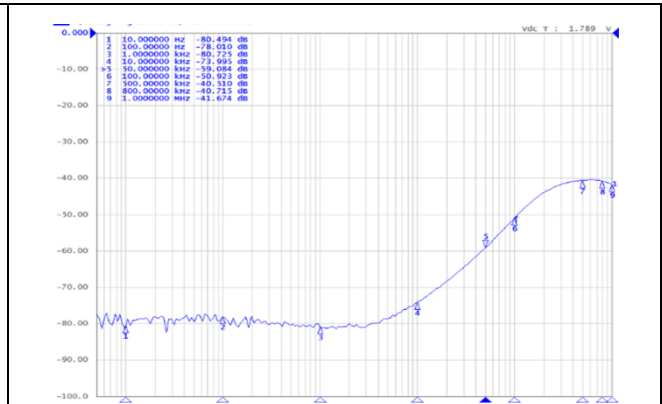
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Typical Characteristics(Continued)

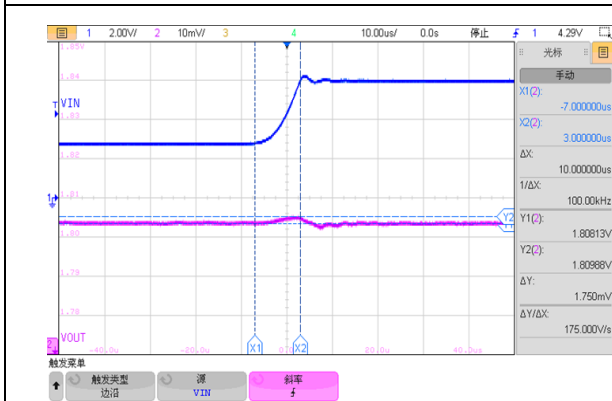
(ET52318YB, $V_{IN} = 2.8V$, $I_{OUT} = 1mA$, $C_{IN} = \text{Ceramic } 1.0\mu F$, $C_{OUT} = \text{Ceramic } 1.0\mu F$, $T_A = -40^{\circ}C \sim 85^{\circ}C$)



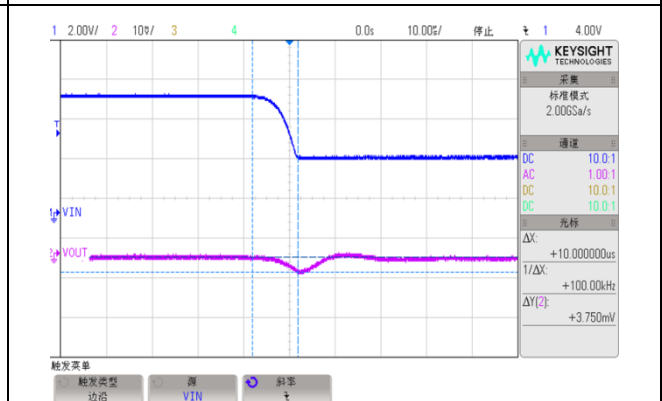
$T_{OFF} (I_{OUT}=30mA)$



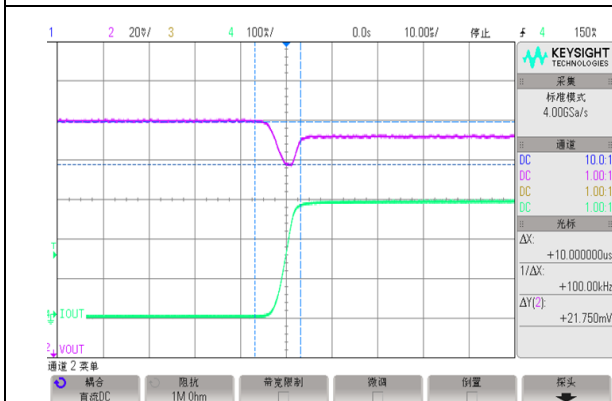
$PSRR (I_{OUT}=20mA)$



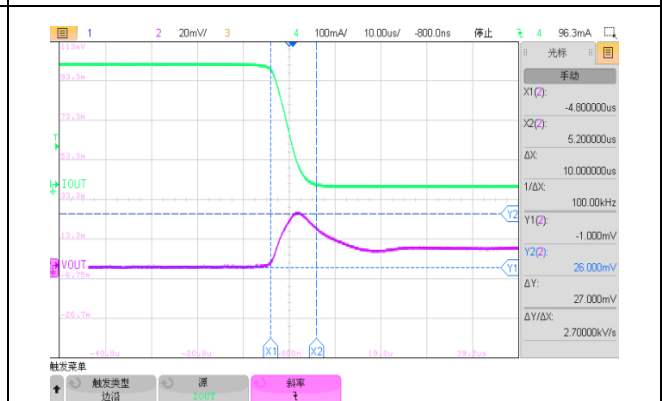
Input Transient(2.8~6V t=10us 1mA)



Input Transient(6~2.8V t=10us 1mA)



Load Transient(1mA~300mA t=10us)

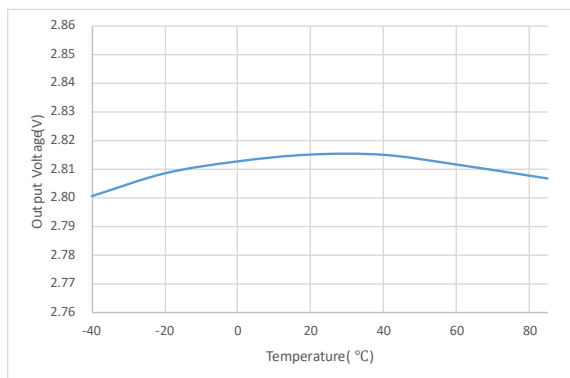


Load Transient(300mA~1mA t=10us)

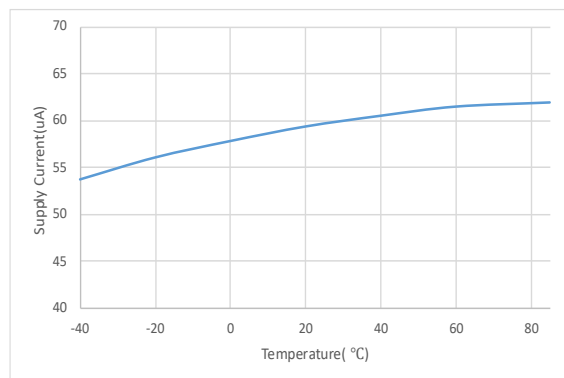
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Typical Characteristics(Continued)

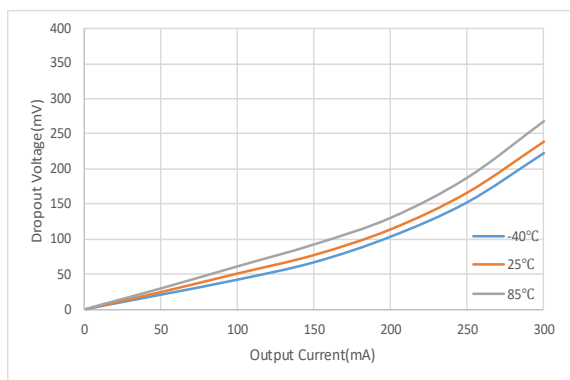
(ET52328YB, $V_{IN}=3.8V$, $I_{OUT}=1mA$, C_{IN} = Ceramic $1.0\mu F$, C_{OUT} = Ceramic $1.0\mu F$, $T_A=-40^{\circ}C\sim 85^{\circ}C$)



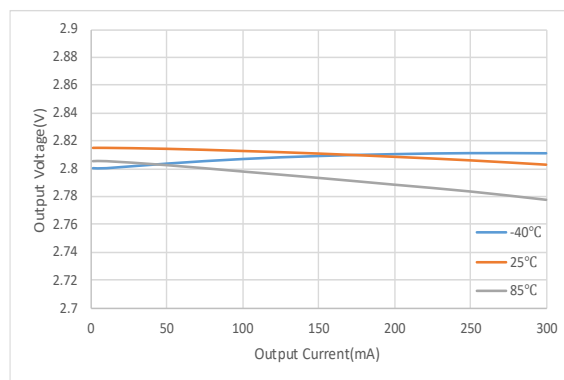
Output Voltage VS Temperature



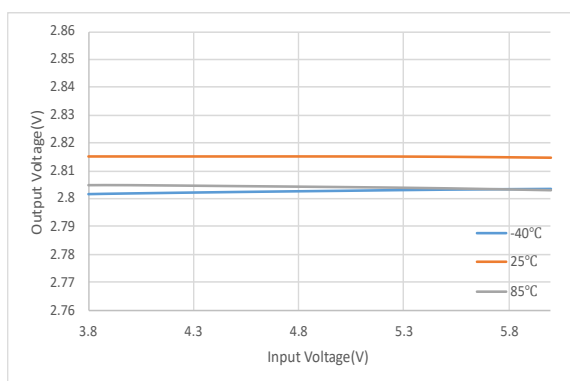
Supply Current VS Temperature



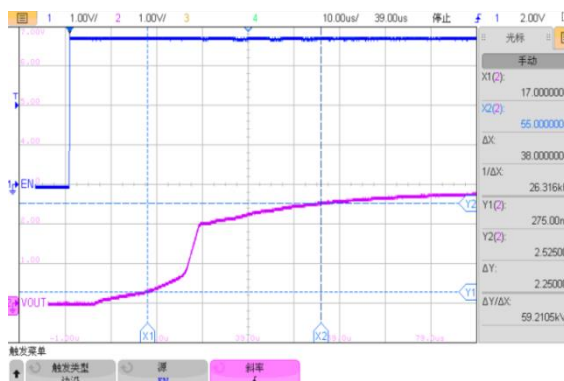
Dropout Voltage VS Output Current



Output Voltage VS Output Current



Output Voltage VS Input Voltage

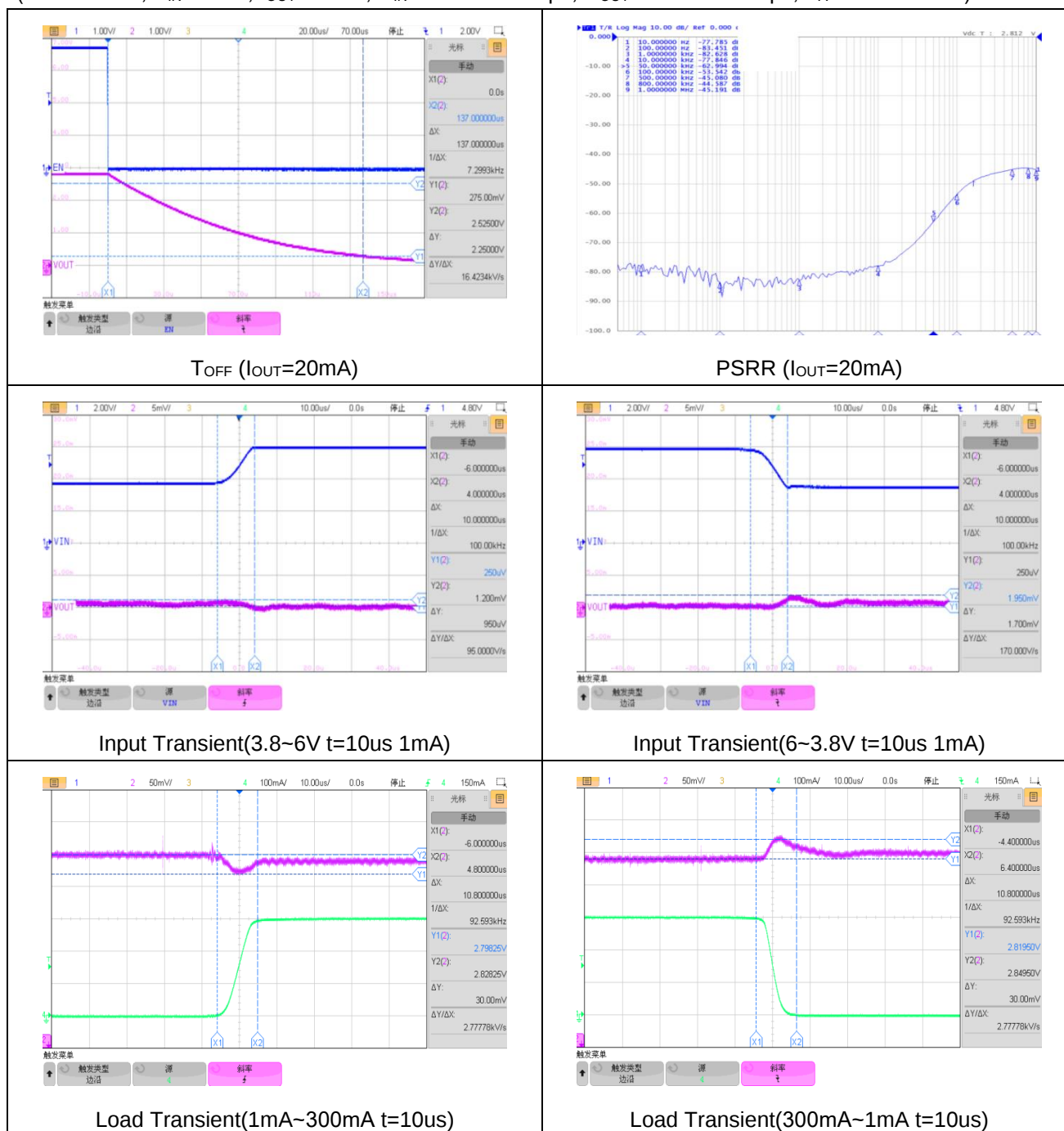


T_{ON} ($I_{OUT}=20mA$)

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Typical Characteristics(Continued)

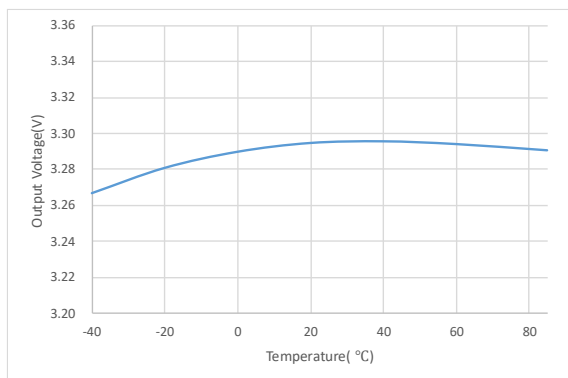
(ET52328YB, $V_{IN} = 3.8V$, $I_{OUT} = 1mA$, $C_{IN} = \text{Ceramic } 1.0\mu F$, $C_{OUT} = \text{Ceramic } 1.0\mu F$, $T_A = -40^{\circ}C \sim 85^{\circ}C$)



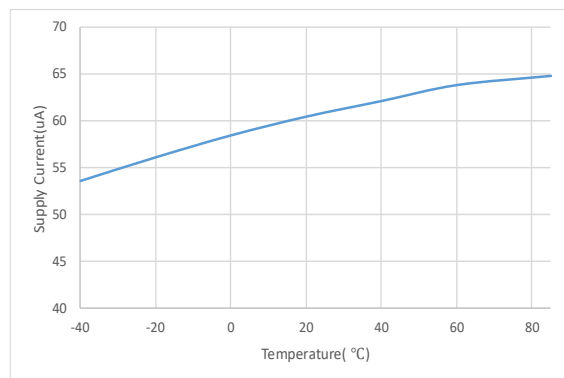
ET523XX

Typical Characteristics(Continued)

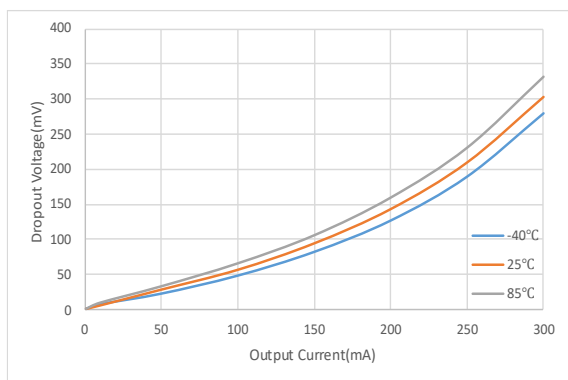
(ET52333YB, $V_{IN}=4.3V$, $I_{OUT}=1mA$, C_{IN} = Ceramic $1.0\mu F$, C_{OUT} = Ceramic $1.0\mu F$, $T_A=-40^{\circ}C\sim 85^{\circ}C$)



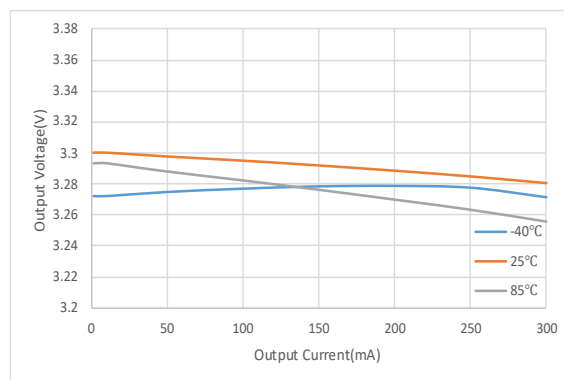
Output Voltage VS Temperature



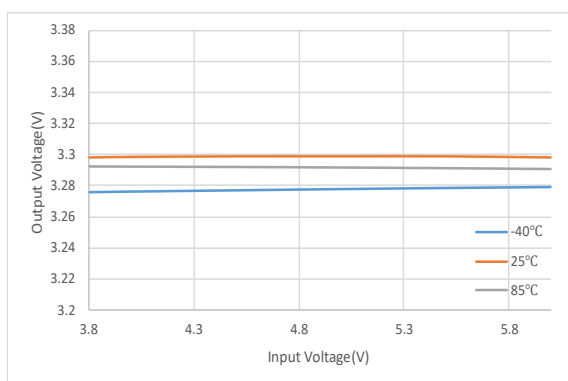
Supply Current VS Temperature



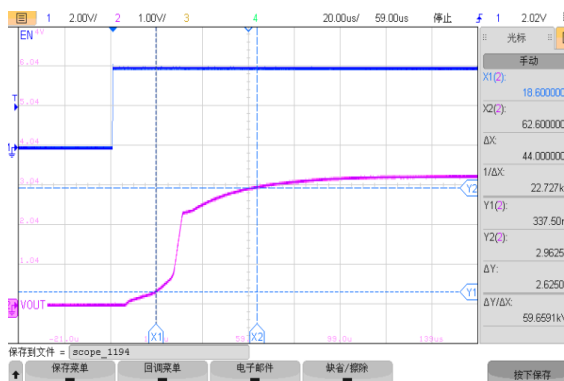
Dropout Voltage VS Output Current



Output Voltage VS Output Current



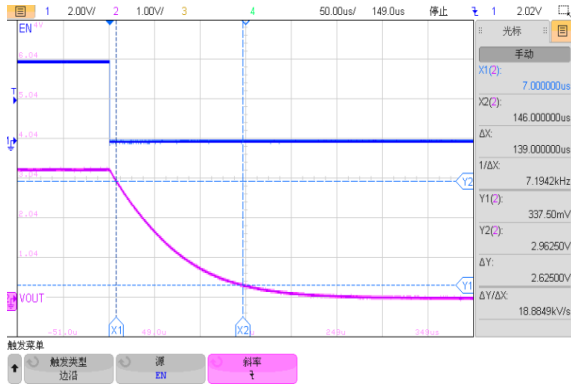
Output Voltage VS Input Voltage



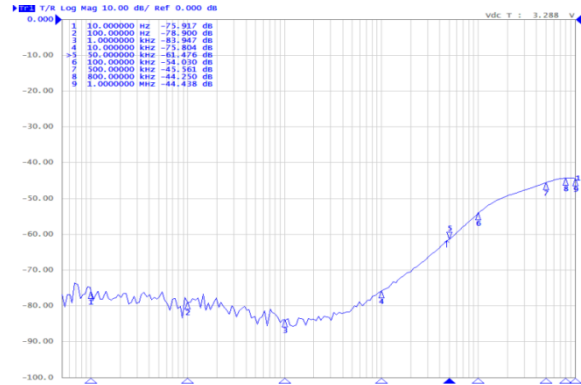
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Typical Characteristics(Continued)

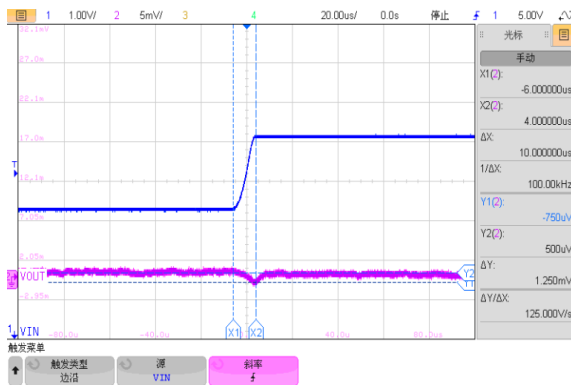
(ET52333YB, $V_{IN} = 4.3V$, $I_{OUT} = 1mA$, $C_{IN} = \text{Ceramic } 1.0\mu F$, $C_{OUT} = \text{Ceramic } 1.0\mu F$, $T_A = -40^{\circ}C \sim 85^{\circ}C$)



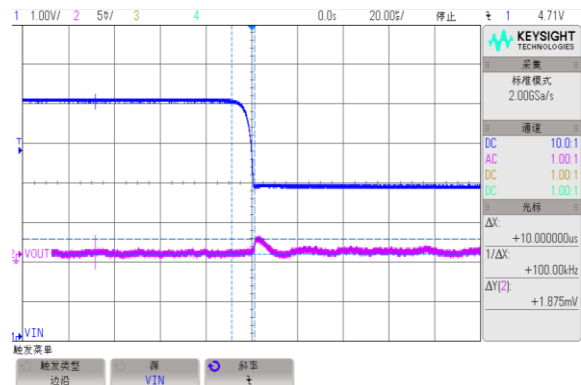
T_{OFF} ($I_{OUT}=20mA$)



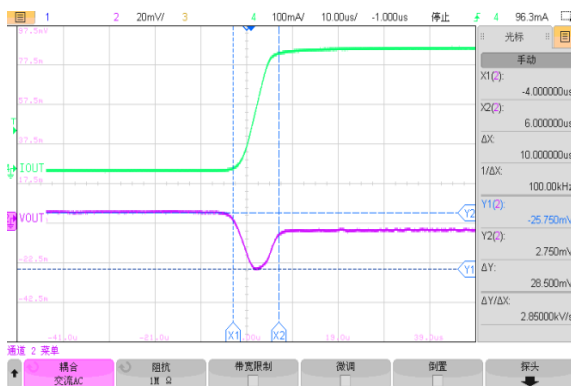
PSRR ($I_{OUT}=20mA$)



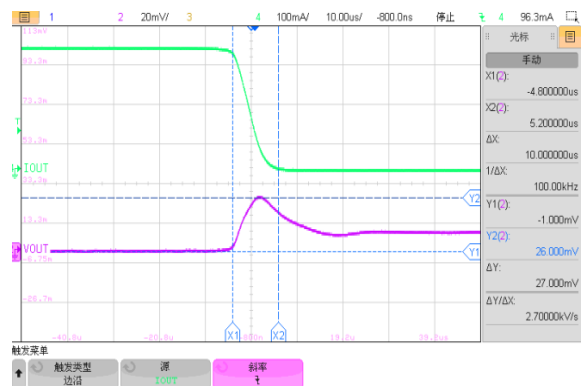
Input Transient(4.3~6V $t=10\mu s$ 1mA)



Input Transient(6~4.3V $t=10\mu s$ 1mA)



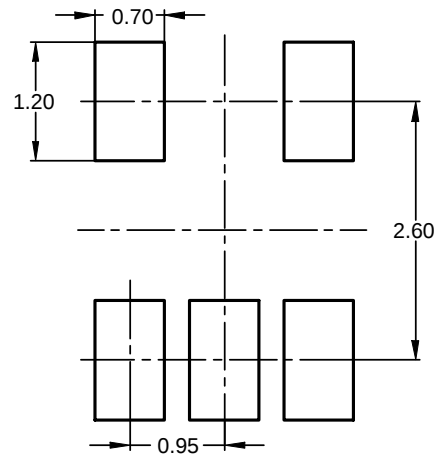
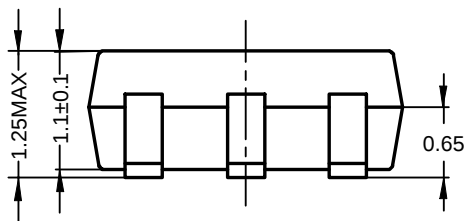
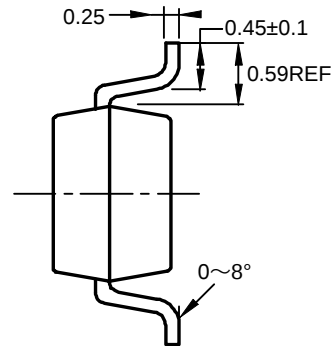
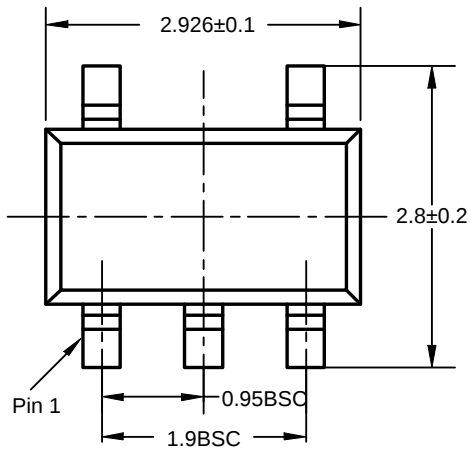
Load Transient(1mA~300mA $t=10\mu s$)



Load Transient(300mA~1mA $t=10\mu s$)

ET523XX

SOT23-5



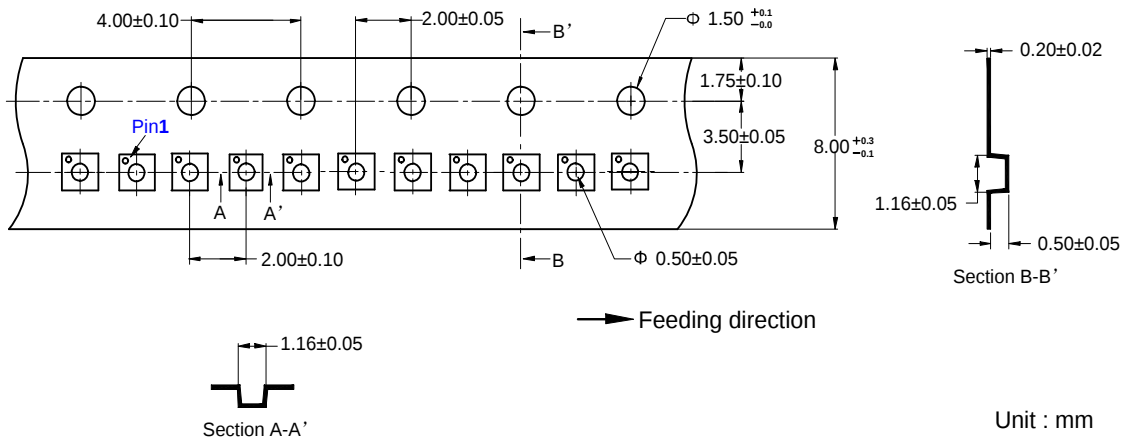
Recommended Land Pattern

Unit: mm

ET523XX

Tape Information

DFN4



Marking

DFN4 Package


$$X^{(1)} = \text{Track Number}$$

$X^{(2)} = V_{OUT}$ Version

Revision History and Checking Table

Version	Date	Revision Item	Modifier	Function & Spec Checking	Package & Tape Checking
0.0	2020-07-08	Original Version	Wangp	Liuxm	Liuju
1.0	2020-11-02	Official Version	Yangxx	Liuxm	Liuju
1.1	2025-01-23	Add 1.2V Output	Yangxx	Liuxm	Liuju
1.2	2025-04-01	Add POD B Shape	Wangp	Liuxm	Liuju
1.3	2025-05-30	Add SOT23-5 package	Yangxx	Liuxm	Liuju